	ESC	C	D	OCUMENT	CHANGE REQUEST			
DCR number	381	Changes red	quired for: Ge	neral	Originator: S Jeffery			
Date: 2007/10	/16	Date sent: 2	2007/10/16		Organisation: ESA/ESTEC			
Status: IMPLE	Status: IMPLEMENTED							
Title:	Transistors Field-E	ffect N-Chann	el, based on ty	pes 2N4391/2N43	92 and 2N4393			
Number:	5205/003		Issue:	1				
Other documen	ts affected:							
Page:								
Total re-write.								
Paragraph:								
Total re-write.								
Original wording	<b>j</b> :							
Proposed wordi	ng:							
	of this specification a tached Issue 2 Draf	•		sion to the ESCC f	format. See below for summary of			
Note: Known su	upport for active proc	curement agai	nst this specific	ation includes the	following manufacturers:			
SEMELAB/UK	(not ESCC qualified	but are curren	tly willing to su	pport the procurer	ment of Variants 01, 02 and 03).			
Summary of cha	anges to the current	format, layout	and content is	as follows:				
-	nd restructuring of v nd editorial content o			•	ation, plus other editorial changes based to ESCC format.			
2. Deletion of re	edundant paragraph	s and informat	ion such as Me	echanical Requirer	nents.			
3. Maximum Ratings table: Remark "Over entire operating temperature range" added for Drain-Source, Gate-Source and Gate-Drain voltages.								
	tings table: Charact .C" corrected to "Ta		•	on (See Figure 1)"	re-named "Power Dissipation"; remark			
	e following note to t performed at Tamb		-		in-lead plating or hot solder dip lead ert atmosphere.".			

	SC		DOCUMENT	CHANGE REQUEST		
DCR number	381	Changes required for:	General	Originator: S Jeffery		
Date: 2007/10/16		Date sent: 2007/10/16		Organisation: ESA/ESTEC		
Status: IMPLEMEN	TED					
6. Figure 1 Paramete	r Derating Inf	ormation moved to be a no	ote to the Maximum R	atings table.		
7. Para. 4.3.2 Weight	requirements	moved to Component Ty	pe Variants table.			
8. Figure 2 re-named package. Notes ame	-	nensions and Terminal Ide	entification" and amen	ded to reflect the 'standardised' TO-18		
9. Figure 3, Function	al Diagram: A	mended (note added).				
		eric Specification: Deviatio rformed) and re-written pe		emperature Reverse Bias Burn-in is meric Specification.		
11. Para. 4.4.1 Case	requirements	corrected to reflect the TC	D-18 metal can packag	ge.		
12. Para. 4.4.2 Lead	Material and	Finish replaced by a refere	ence to the Componer	nt Type Variants Para.		
13. Para. 4.5.1 Requ qualified components	•	•	fication deleted (not a	pplicable to "TO-" packages) and ESCC		
14. Delete requireme 21700.	nt for marking	of the test level letter from	n the ESCC Compone	ent Number as per latest ESCC No.		
15. Table 2, Characte	eristic "Total G	ate Leakage Current" re-r	named "Gate Reverse	Leakage Current".		
16. Table 2, Characteristic "Gate Source Breakdown Voltage" re-named "Gate-Source Breakdown Voltage"; IG Test Condition corrected (was â1.0ÂμA, now 1ÂμΑ).						
17. Table 2, Characte (was VGSoff, now VC		ource Cut-off Voltage" re-	named "Gate-Source	Cut-off Voltage" and Symbol amended		
18. Table 2, Characte amended (was VDsa		-	' re-named "Drain-Soเ	urce Saturation Voltage" and Symbol		
		ate Drain Source Resistan (was rDSon, now rDS(on)	, ,	"Static ON-State Drain-Source		
		ate Drain Source Resistan (was rDSon, now rds(on))	. ,	"Small-Signal ON-State Drain-Source		
21. Table 2, Characte VDS Test Condition of	•	•	mall-Signal Common-	Source Short-Circuit Input Capacitance";		
22. Table 2, Characte	eristic "Revers	e Transfer Capacitance" r	e-named "Small-Sign	al Common-Source Short-Circuit Reverse		

	S		DOCUMENT	CHANGE REQUEST		
DCR number	381	Changes required for:	General	Originator: S Jeffery		
Date: 2007/10/16		Date sent: 2007/10/16		Organisation: ESA/ESTEC		
Status: IMPLEMEN	TED					
Transfer Capacitance	)".					
		Time", "Turn-on Delay Tin Test Conditions amended		urn-off Delay Time" revised (Test Method		
24. Table 2: Samplin 100%).	g note for AC	C parameters tests amende	ed to be a fixed sample	of 32 components with 0 failures (or		
25. Figure 4 amende	d and moved	d to be a note (Note 3) to R	oom Temperature Ele	ctrical Measurements.		
26. Table 3, Characte test temperature.	eristic "Total	Gate Leakage Current" re-	named "Gate Reverse	Leakage Current"; tolerance added to		
27. Table 3, Characte	eristic "Drain	Cut-off Current": Tolerance	e added to test temper	ature.		
, ,	•	erature Electrical Measurer 0%, in line with the new Ge	· · ·	on has been replaced by a sample of 5		
29. Table 4: 'Spec and/or Test Method' and 'Test Conditions' columns removed; absolute limits have been added for information.						
30. Table 4, Characteristic "Total Gate Leakage Current" re-named "Gate Reverse Leakage Current"; note reference changed from 2 to 1.						
31. Table 4, Characteristic "Gate Source Cut-off Voltage" re-named "Gate-Source Cut-off Voltage"; Symbol amended (was VGSoff, now VGS(off)).						
32. Table 4: Notes ar	nended (Not	e 1 deleted and Note 2 re-	worded and re-number	red Note 1).		
33. Tables 2, 3 and 4 Methods as and whe			est, or Bias, Conditior	ns for referenced MIL-STD-750 Test		
34. Table 5 amended: Tolerance added to test temperature; Test Method and condition added as required by the new Generic 5000 Issue 3						
35. Figure 5 deleted.						
36. Table 6, Characte	eristic "Total	Gate Leakage Current" re-	named "Gate Reverse	Leakage Current".		
37. Table 6, Characte VGSoff, now VGS(of		Source Cut-off Voltage" re-	named "Gate-Source	Cut-off Voltage"; Symbol amended (was		
38. Table 6: 'Spec ar	d/or Test Me	ethod', 'Test Conditions' col	umns and Note 1 rem	oved		

	SC	DOCUMENT	CHANGE REQUEST			
DCR number	381	Changes required for: General	Originator: S Jeffery			
Date: 2007/10/16		Date sent: 2007/10/16	Organisation: ESA/ESTEC			
Status: IMPLEMENT	ſED					
Justification:						
(see also change deta	ails for each ite	em above)				
1. Part of the ongoing	activity of con	version of cover-sheeted ESA/SCC Specificati	ons to the ESCC format.			
2. To make the format ESCC format.	t and presenta	tion consistent with the various other ESCC De	etail Specifications already converted to			
3. To make the conter	nt consistent w	vith ESCC Generic Specification No. 5000 Issu	e 3.			
4. To introduce a stan	dard note abo	ut testing at temperatures >+125deg.C which v	vas missing from the previous issue.			
5. To make correction	s to technical	errors in the previous issue.				
6. Standardisation of t	the TO-18 pac	kage in all applicable ESCC Detail Specificatio	ns.			
Attachments:						
5205003_lssue_2[	Draft_A.pdf, nเ	<b>J</b> II				
Modifications:						
N/A						
Approval signature:						
R. C. Hari-						
Date signed:						
2007-10-16						



Pages 1 to 13

# **TRANSISTORS, FIELD-EFFECT, N-CHANNEL**

# BASED ON TYPE 2N4391, 2N4392 AND 2N4393

ESCC Detail Specification No. 5205/003

Issue 2 - Draft A	October 2007



Document Custodian: European Space Agency - see https://escies.org



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PAGE 3 ISSUE 2 - Draft A

## **DOCUMENTATION CHANGE NOTICE**

(Refer to https://escies.org for ESCC DCR content)

DCR No.	CHANGE DESCRIPTION
TBD	Specification up issued to incorporate editorial and technical changes per DCR.



PAGE 4 ISSUE 2 - Draft A

# TABLE OF CONTENTS

<u>1.</u>	GENERAL	<u>5</u>
1.1	Scope	5
1.2	Applicable Documents	5
1.3	Terms, Definitions, Abbreviations, Symbols and Units	5
1.4	The ESCC Component Number and Component Type Variants	5
1.4.1	The ESCC Component Number	5
1.4.2	Component Type Variants	5
1.5	Maximum Ratings	5
1.6	Physical Dimensions and Terminal Identification	6
1.6.1	Metal Can Package (TO-18) - 3 lead	6
1.7	Functional Diagram	7
1.8	Materials and Finishes	7
<u>2.</u>	REQUIREMENTS	<u>8</u>
<u></u>		_
<u></u> 2.1	General	8
	General Deviations from the Generic Specification	
2.1		8
2.1 2.1.1	Deviations from the Generic Specification	8 8
2.1 2.1.1 2.2	Deviations from the Generic Specification Marking	8 8 8
2.1 2.1.1 2.2 2.3	Deviations from the Generic Specification Marking Terminal Strength	8 8 8 8
2.1 2.1.1 2.2 2.3 2.4	Deviations from the Generic Specification Marking Terminal Strength Electrical Measurements at Room, High and Low Temperatures	8 8 8 8 8
2.1 2.1.1 2.2 2.3 2.4 2.4.1	Deviations from the Generic Specification Marking Terminal Strength Electrical Measurements at Room, High and Low Temperatures Room Temperature Electrical Measurements	8 8 8 8 8 8
2.1 2.1.1 2.2 2.3 2.4 2.4.1 2.4.2	Deviations from the Generic Specification Marking Terminal Strength Electrical Measurements at Room, High and Low Temperatures Room Temperature Electrical Measurements High and Low Temperatures Electrical Measurements	8 8 8 8 8 11
2.1 2.1.1 2.2 2.3 2.4 2.4.1 2.4.2 2.5	Deviations from the Generic Specification Marking Terminal Strength Electrical Measurements at Room, High and Low Temperatures Room Temperature Electrical Measurements High and Low Temperatures Electrical Measurements Parameter Drift Values	8 8 8 8 8 11 12



#### 1. <u>GENERAL</u>

#### 1.1 <u>SCOPE</u>

This specification details the ratings, physical and electrical characteristics and test and inspection data for the component type variants and/or the range of components specified below. It supplements the requirements of, and shall be read in conjunction with, the ESCC Generic Specification listed under Applicable Documents.

#### 1.2 <u>APPLICABLE DOCUMENTS</u>

The following documents form part of this specification and shall be read in conjunction with it:

- (a) ESCC Generic Specification No. 5000
- (b) MIL-STD-750, Test Methods and Procedures for Semiconductor Devices

#### 1.3 TERMS, DEFINITIONS, ABBREVIATIONS, SYMBOLS AND UNITS

For the purpose of this specification, the terms, definitions, abbreviations, symbols and units specified in ESCC Basic Specification No. 21300 shall apply.

#### 1.4 THE ESCC COMPONENT NUMBER AND COMPONENT TYPE VARIANTS

# 1.4.1 <u>The ESCC Component Number</u> The ESCC Component Number shall be constituted as follows:

Example: 520500301

- Detail Specification Reference: 5205003
- Component Type Variant Number: 01 (as required)

#### 1.4.2 <u>Component Type Variants</u>

The component type variants applicable to this specification are as follows:

Variant Number	Based on Type	Case	Lead/Terminal Material and Finish	Weight max g
01	2N4391	TO-18	D2	0.9
02	2N4392	TO-18	D2	0.9
03	2N4393	TO-18	D2	0.9

The lead/terminal material and finish shall be in accordance with the requirements of ESCC Basic Specification No. 23500.

#### 1.5 MAXIMUM RATINGS

The maximum ratings shall not be exceeded at any time during use or storage.

Maximum ratings shall only be exceeded during testing to the extent specified in this specification and



ISSUE 2 - Draft A

PAGE 6

Characteristics	Symbols	Maximum Ratings	Unit	Remarks
Drain-Source Voltage	V <sub>DS</sub>	40	V	Over entire
Gate-Source Voltage	V <sub>GS</sub>	-40	V	operating temperature
Gate-Drain Voltage	V <sub>GD</sub>	-40	V	range
Gate Current	۱ <sub>G</sub>	50	mA	
Power Dissipation	P <sub>tot</sub>	300	mW	At T <sub>amb</sub> ≤ +25°C Note 1
Operating Temperature Range	T <sub>op</sub>	-55 to +175	°C	Note 2
Storage Temperature Range	T <sub>stg</sub>	-65 to + 200	°C	Note 2
Soldering Temperature	T <sub>sol</sub>	+235	°C	Note 3

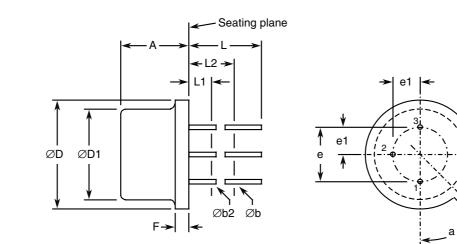
when stipulated in Test Methods and Procedures of the ESCC Generic Specification.

#### NOTES:

- 1.
- For  $T_{amb} > +25^{\circ}$ C, derate linearly to 0W at +175°C. For Variants with tin-lead plating or hot solder dip lead finish all testing performed at  $T_{amb} > +125^{\circ}$ C 2. shall be carried out in a 100% inert atmosphere.
- Duration 10 seconds maximum at a distance of not less than 1.5mm from the device body and the 3. same lead shall not be resoldered until 3 minutes have elapsed.

#### 1.6 PHYSICAL DIMENSIONS AND TERMINAL IDENTIFICATION

#### 1.6.1 Metal Can Package (TO-18) - 3 lead



Symbols	Dimensio	Notes	
- Oymbola	Min	Max	Notes
A	4.32	5.33	
Øb	0.406	0.533	2, 3

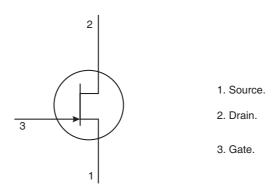


Symbols	Dimensio	Notes	
Symbols	Min	Max	Notes
Øb2	0.406	0.483	2, 3
ØD	5.31	5.84	
ØD1	4.52	4.95	
е	2.54 I	BSC	4
e1	1.27 BSC		4
F	-	0.762	
j	0.914	1.17	
k	0.711	1.22	5
L	12.7	-	2
L1	-	1.27	3
L2	6.35	-	3
а	45° E	BSC	1, 4, 6

#### NOTES:

- 1. Terminal identification is specified by reference to the tab position where lead 1 = source, lead 2 = drain, lead 3 = gate.
- 2. Applies to all leads.
- 3. Øb2 applies between L1 and L2. Øb applies between L2 and 12.7mm from the seating plane. Diameter is uncontrolled within L1 and beyond 12.7mm from the seating plane.
- 4. Leads having maximum diameter 0.483mm measured in the gauging plane 1.37(+0.025,-0)mm below the seating plane of the device shall be within 0.178mm of their true position relative to a maximum-width-tab.
- 5. Measured from the maximum diameter of the actual device.
- 6. Tab centreline.

#### 1.7 <u>FUNCTIONAL DIAGRAM</u>



#### NOTES:

1. The gate is internally connected to the case.



ISSUE 2 - Draft A

## 1.8 <u>MATERIALS AND FINISHES</u>

Materials and finishes shall be as follows:

- a) Case The case shall be hermetically sealed and have a metal body with hard glass seals.
- b) Leads/Terminals As specified in Component Type Variants.

#### 2. <u>REQUIREMENTS</u>

#### 2.1 <u>GENERAL</u>

The complete requirements for procurement of the components specified herein are as stated in this specification and the ESCC Generic Specification. Permitted deviations from the Generic Specification, applicable to this specification only, are listed below.

Permitted deviations from the Generic Specification and this Detail Specification, formally agreed with specific Manufacturers on the basis that the alternative requirements are equivalent to the ESCC requirement and do not affect the component's reliability, are listed in the appendices attached to this specification.

#### 2.1.1 Deviations from the Generic Specification

(a) Deviation from Screening Tests - Chart F3 Power Burn-in and the subsequent Parameter Drift Values (Final Measurements) shall be omitted.

#### 2.2 <u>MARKING</u>

The marking shall be in accordance with the requirements of ESCC Basic Specification No. 21700 and as follows.

The information to be marked on the component shall be:

- (a) The ESCC qualified components symbol (for ESCC qualified components only).
- (b) The ESCC Component Number.
- (c) Traceability information.

#### 2.3 <u>TERMINAL STRENGTH</u>

The test conditions for terminal strength, tested as specified in the ESCC Generic Specification, shall be as follows:

Test Condition: A, tension, with an applied force of 5N for a duration of 10s.

- 2.4 <u>ELECTRICAL MEASUREMENTS AT ROOM, HIGH AND LOW TEMPERATURES</u> Electrical measurements shall be performed at room, high and low temperatures.
- 2.4.1 Room Temperature Electrical Measurements The measurements shall be performed at  $T_{amb}$ =+22 ±3°C.



ISSUE 2 - Draft A

Characteristics	Symbols	MIL-STD-750	Test Conditions	Lir	Limits	
		Test Method		Min	Max	
Gate Reverse Leakage Current	I <sub>GSS</sub>	3411	V <sub>GS</sub> =-20V Bias condition C	-	-100	рА
Gate-Source Breakdown Voltage	V <sub>(BR)GSS</sub>	3401	$I_G=1\mu A$ Bias condition C	-40	-	V
Drain Cut-off Current	I <sub>DSX</sub>	3413	$\begin{array}{l} V_{DS} = 20V \\ Variant 01: V_{GS} = -12V \\ Variant 02: V_{GS} = -7V \\ Variant 03: V_{GS} = -5V \\ Bias \ condition \ A \end{array}$	-	100	рА
Drain Current Variant 01 Variant 02 Variant 03	I <sub>DSS</sub>	3413	V <sub>DS</sub> =20V Bias condition C Note 1	50 25 5	150 75 30	mA
Gate-Source Cut- off Voltage Variant 01 Variant 02 Variant 03	V <sub>GS(off)</sub>	3403	V <sub>DS</sub> =20V I <sub>D</sub> =1nA	-4 -2 -0.5	-10 -5 -3	V
Drain-Source Saturation Voltage	V <sub>DS(sat)</sub>	3405	Variant 01: $I_D=12mA$ Variant 02: $I_D=6mA$ Variant 03: $I_D=3mA$ Bias condition B	-	400	mV
Static ON-State Drain-Source Resistance Variant 01 Variant 02 Variant 03	r <sub>DS(on)</sub>	3421	I <sub>D</sub> =1mA Bias condition B	- - -	30 60 100	Ω
Small-Signal ON- State Drain- Source Resistance Variant 01 Variant 02 Variant 03	r <sub>ds(on)</sub>	3423	I <sub>D</sub> =0A f=1kHz Bias condition B Note 2	- - -	30 60 100	Ω
Small-Signal Common-Source Short-Circuit Input Capacitance	C <sub>iss</sub>	3431	V <sub>GS</sub> =0V V <sub>DS</sub> =20V f=1MHz Note 2	-	26	pF



ISSUE 2 - Draft A

Characteristics	Symbols	MIL-STD-750	Test Conditions	Limits		Units
		Test Method		Min	Max	
Small-Signal Common-Source Short-Circuit Reverse Transfer Capacitance	C <sub>rss</sub>	3433	$\label{eq:VDS} \begin{array}{l} V_{DS} = 0V \\ f = 1 MHz \\ Variant 01: V_{GS} = -12V \\ Variant 02: V_{GS} = -7V \\ Variant 03: V_{GS} = -5V \\ Note 2 \end{array}$	-	4	pF
Rise Time	tr	3459	$\label{eq:VDD} \begin{array}{l} V_{DD} = 10V \\ V_{GS} = 0V \\ Variant 01: \\ V_{GSX} = -12V, \\ I_{D(on)} = 12mA \\ Variant 02: \\ V_{GSX} = -7V, \ I_{D(on)} = 6mA \\ Variant 03: \\ V_{GSX} = -5V, \ I_{D(on)} = 3mA \\ Notes 2, \ 3 \end{array}$	-	5	ns
Turn-on Delay Time	t <sub>d(on)</sub>	3459	$\label{eq:spectral_state} \begin{array}{l} V_{DD} = 10V \\ V_{GS} = 0V \\ Variant 01: \\ V_{GSX} = -12V, \\ I_{D(on)} = 12mA \\ Variant 02: \\ V_{GSX} = -7V, \ I_{D(on)} = 6mA \\ Variant 03: \\ V_{GSX} = -5V, \ I_{D(on)} = 3mA \\ Notes 2, 3 \end{array}$	-	15	ns
Fall Time	t <sub>f</sub>	3459	$\label{eq:VDD} \begin{array}{l} V_{DD} = 10V \\ V_{GS} = 0V \\ Variant 01: \\ V_{GSX} = -12V, \\ I_{D(on)} = 12mA \\ Variant 02: \\ V_{GSX} = -7V, \ I_{D(on)} = 6mA \\ Variant 03: \\ V_{GSX} = -5V, \ I_{D(on)} = 3mA \\ Notes 2, 3 \end{array}$	- - -	15 20 30	ns
Turn-off Delay Time	t <sub>d(off)</sub>	3459	$\label{eq:VDD} \begin{array}{l} V_{DD} = 10V \\ V_{GS} = 0V \\ Variant 01: \\ V_{GSX} = -12V, \\ I_{D(on)} = 12mA \\ Variant 02: \\ V_{GSX} = -7V, \ I_{D(on)} = 6mA \\ Variant 03: \\ V_{GSX} = -5V, \ I_{D(on)} = 3mA \\ Notes 2, 3 \end{array}$	- -	20 35 50	ns

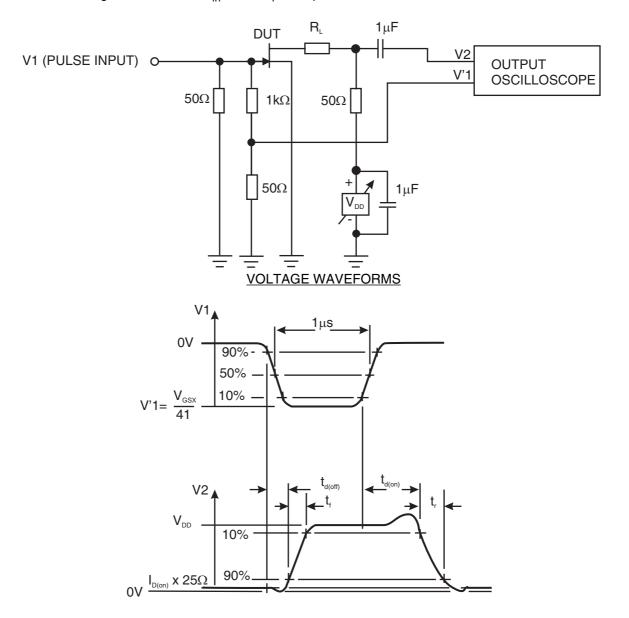
NOTES:

Pulsed measurement: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
 For AC characteristics read and record measurements shall be performed on a sample of 32



components with 0 failures allowed. Alternatively a 100% inspection may be performed.

3.  $t_r$ ,  $t_{d(on)}$ ,  $t_f$  and  $t_{d(off)}$  shall be measured using the following test circuit. The input waveform shall be supplied by a pulse generator with the following characteristics:  $Z_{out} = 50\Omega$ ,  $t_r = t_f \le 500$ ps, Pulse Width = 1µs, Duty Cycle = 10%. The output waveform shall be monitored on an oscilloscope with the following characteristics:  $Z_{in} = 50\Omega$ ,  $t_r \le 400$ ps.



#### 2.4.2 High and Low Temperatures Electrical Measurements

Characteristics	Symbols	MIL-STD-750		Limits		Units
		Test Method	Note 1	Min	Max	
Gate Reverse Leakage Current	I <sub>GSS</sub>	3411	$T_{amb}$ =+150(+0-5)°C V <sub>GS</sub> =-20V Bias condition C	-	-200	nA



ISSUE 2 - Draft A

Characteristics		MIL-STD-750	Test Conditions	Limits		Units
		Test Method	Note 1	Min	Max	
Drain Cut-off Current	I <sub>DSX</sub>	3413	$T_{amb}=+150(+0-5)^{\circ}C$ $V_{DS}=20V$ Variant 01:V <sub>GS</sub> =-12V Variant 02:V <sub>GS</sub> =-7V Variant 03:V <sub>GS</sub> =-5V Bias condition A	-	200	nA

#### NOTES:

1. Read and record measurements shall be performed on a sample of 5 components with 0 failures allowed. Alternatively a 100% inspection may be performed.

#### PARAMETER DRIFT VALUES 2.5

Unless otherwise specified, the measurements shall be performed at  $T_{amb}$ =+22 ±3°C.

The test methods and test conditions shall be as per the corresponding test defined in Room Temperature Electrical Measurements.

The drift values ( $\Delta$ ) shall not be exceeded for each characteristic specified. The corresponding absolute limit values for each characteristic shall not be exceeded.

Characteristics	Symbols		Units			
		Drift	Absolute			
		Value A	Min	Max		
Gate Reverse Leakage Current	I <sub>GSS</sub>	±50 or (1) ±100%	-	-100	рА	
Gate Source Cut-off Voltage Variant 01 Variant 02 Variant 03	V <sub>GS(off)</sub>	±10%	-4 -2 -0.5	-10 -5 -3	V	
Drain Current Variant 01 Variant 02 Variant 03	I <sub>DSS</sub>	±15%	50 25 5	150 75 30	mA	

#### NOTES:

1. Whichever is the greater referred to the initial value.

#### INTERMEDIATE AND END-POINT ELECTRICAL MEASUREMENTS

Unless otherwise specified, the measurements shall be performed at  $T_{amb}$ =+22 ±3°C.

The test methods and test conditions shall be as per the corresponding test defined in Room Temperature Electrical Measurements.

2.6



PAGE 13 ISSUE 2 - Draft A

#### The limit values for each characteristic shall not be exceeded.

Characteristics	Symbols	Limits		Units
		Min	Max	
Gate Reverse Leakage Current	I <sub>GSS</sub>	-	-100	pА
Gate Source Cut-off Voltage Variant 01 Variant 02 Variant 03	V <sub>GS(off)</sub>	-4 -2 -0.5	-10 -5 -3	V
Drain Current Variant 01 Variant 02 Variant 03	I <sub>DSS</sub>	50 25 5	150 75 30	mA

## 2.7 <u>HIGH TEMPERATURE REVERSE BIAS BURN-IN CONDITIONS</u> MIL-STD-750, Test Method 1039, Condition A

Characteristics	Symbols	Test Conditions	Units
Ambient Temperature	T <sub>amb</sub>	+150(+0-5)	°C
Drain-Source Voltage	V <sub>DS</sub>	0	V
Gate-Source Voltage	V <sub>GS</sub>	-28	V
Duration	t	168 to 264	Hours

### 2.8 OPERATING LIFE CONDITIONS

The conditions shall be as specified for High Temperature Reverse Bias Burn-in except the duration shall be as specified in the ESCC Generic Specification.